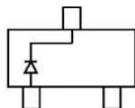
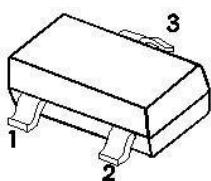


**SOT-23****SOT-23 贴片塑封二极管****SOT-23 Plastic-Encapsulate Diode**

Marking: D3E

**特征 Features**

- 低电流整流。Low current rectification
- 反向漏电流小。Low IR
- 高可靠性。High reliability

**机械数据 Mechanical Data**

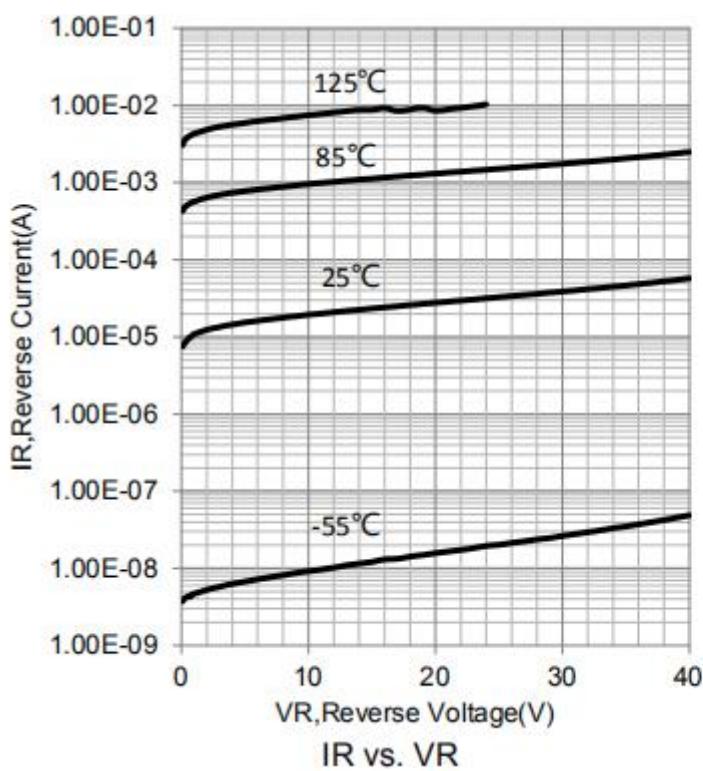
- 封装: SOT-23 封装 SOT-23 Small Outline Plastic Package
- 环氧树脂 UL 易燃等级 Epoxy UL: 94V-0
- 安装位置: 任意 Mounting Position: Any

极限值和温度特性( $TA = 25^\circ\text{C}$  除非另有规定)**Maximum Ratings & Thermal Characteristics** (Ratings at  $25^\circ\text{C}$  ambient temperature unless otherwise specified.)

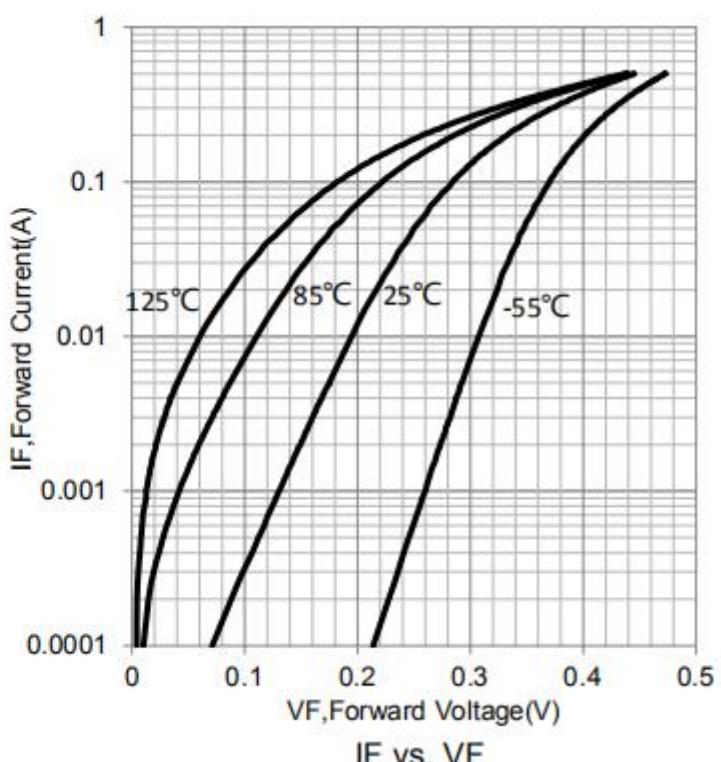
参数 Parameters	符号 Symbol	数值 Value	单位 Unit
反向峰值电压 Peak Repetitive Reverse Voltage	VRM	40	V
反向电压 Reverse Voltage	VR	20	V
平均正向整流电流 Average Rectified Forward Current	IO	500	mA
峰值正向浪涌电流 Forward Current Surge Peak	IFSM	3	A
结温 Junction Temperature	Tj	125	°C
存储温度 Storage temperature range	TSTG	-40-+125	°C

电特性 ( $TA = 25^\circ\text{C}$  除非另有规定)**Electrical Characteristics** (Ratings at  $25^\circ\text{C}$  ambient temperature unless otherwise specified).

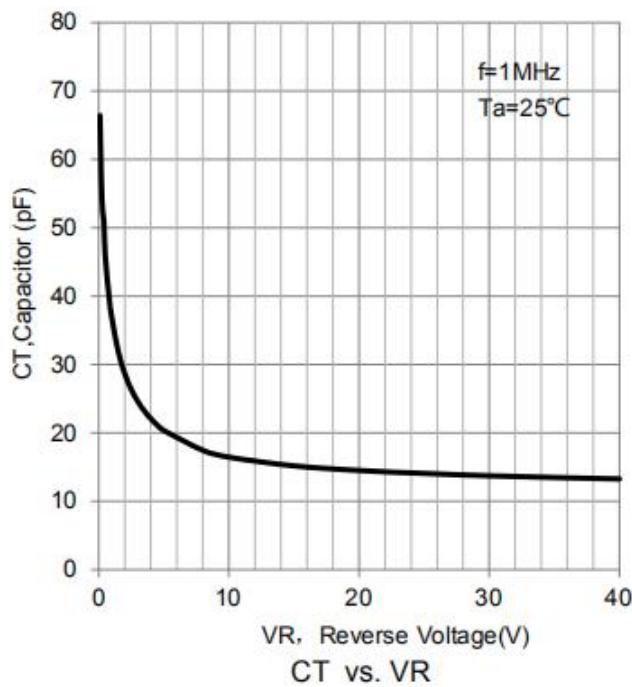
符号 Symbols	参数 Parameter	测试条件 Test Condition	界限 Limits			单位 Unit
			Min	Typ	Max	
VF	正向电压 Forward Voltage	IF=500mA	--	--	0.5	V
		IF=10mA	--	--	0.3	
IR	反向漏电电流 Reverse Leakage Current	VR=10V	--	--	30	uA
CT	结电容 Capacitance Between Terminal	VR=10V, f=1MHZ	--	16	--	pF

**Typical Characteristics**

IR vs. VR

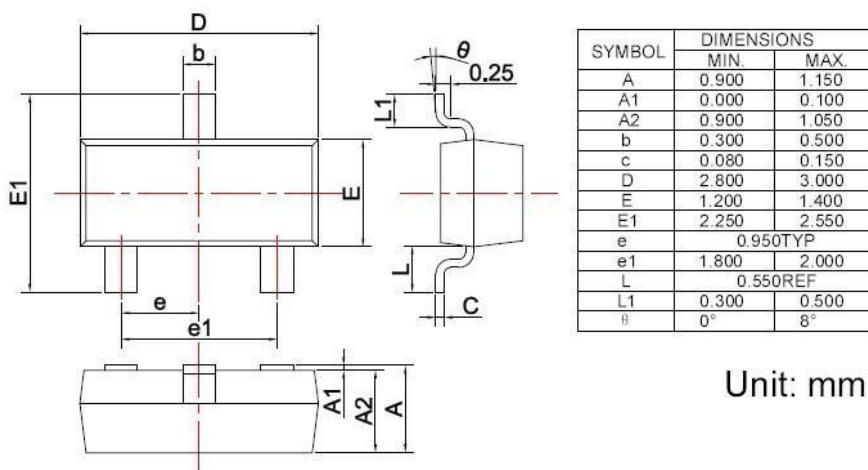


IF vs. VF



CT vs. VR

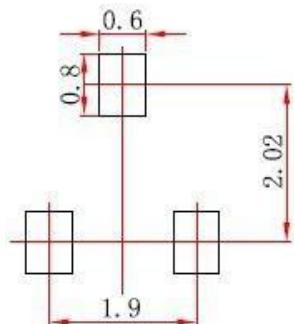
## SOT-23 PACKAGE OUTLINE Plastic surface mounted package



### 焊盘设计参考

Precautions: PCB Design

Recommended land dimensions for SOT-23 diode. Electrode patterns for PCBs



#### Note:

1. Controlling dimension: In millimeters.
2. General tolerance:  $\pm 0.05$  mm.
3. The pad layout is for reference purposes only.